

1-Line Bi-directional TVS Diode

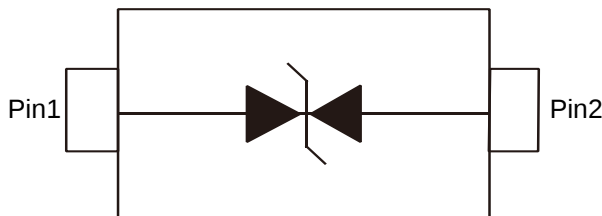
Description

The PESDU4581D3H is a bi-directional high power TVS diode, to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The PESDU4581D3H complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into an ultra-small lead -free SOD-323 package. The small size and high ESD protection make PESDU4581D3H an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- Small SOD-323 package
- Protects one data or power line
- Operating Voltage: 4.5V
- High peak pulse current capability
- Ultra low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 140A (8/20 μs)
- RoHS Compliant

Dimensions and Pin Configuration



Circuit Diagram

Mechanical Characteristics

- Package: SOD-323
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

- Mobile Phones and Accessories
- Battery Protection
- Power Supply Protection
- Hand Held Portable Applications
- Peripherals

Marking Information



48D = Device Marking Code

Ordering Information

Part Number	Shipping	Reel Size
PESDU4581D3H	3000/Tape & Reel	7 inch

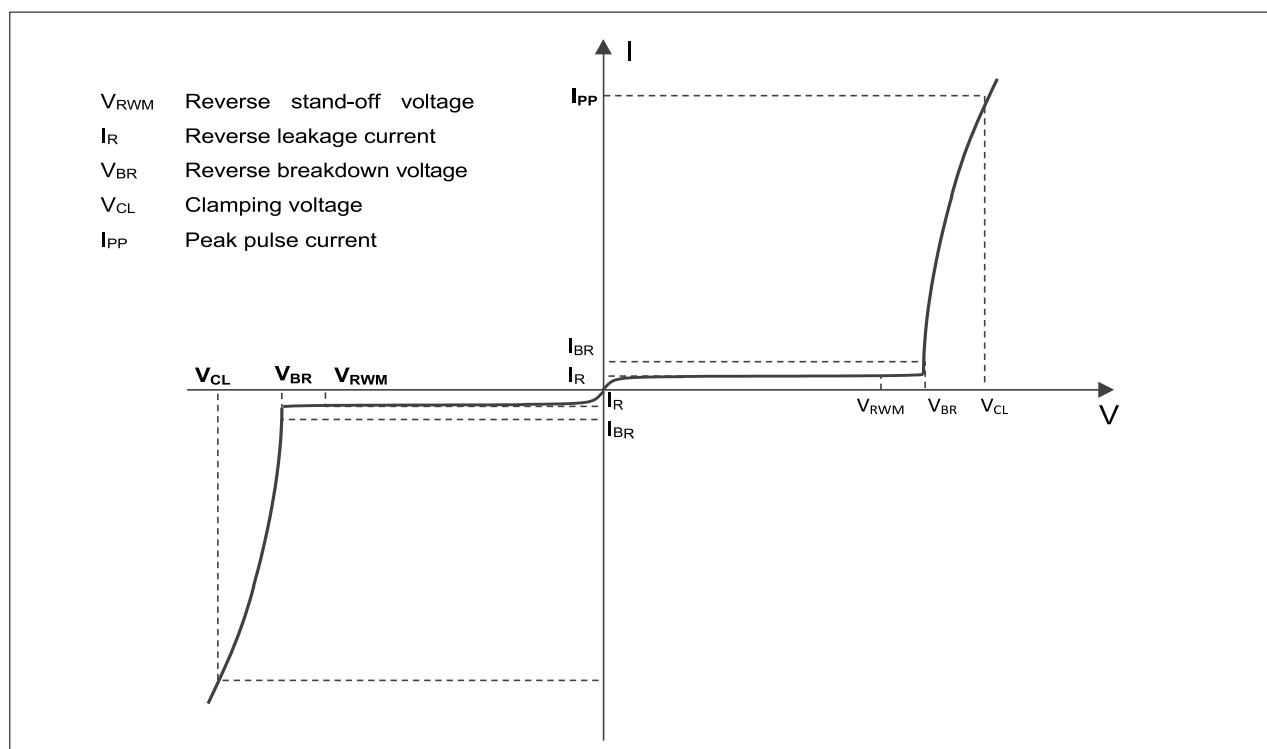
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P _{PK}	2380	W
Peak Pulse Current (8/20μs)	I _{PP}	140	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	kV
Lead temperature	T _L	260	°C
Junction Temperature	T _J	125	°C
Operating Temperature Range	T _{OP}	-40 ~ +125	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

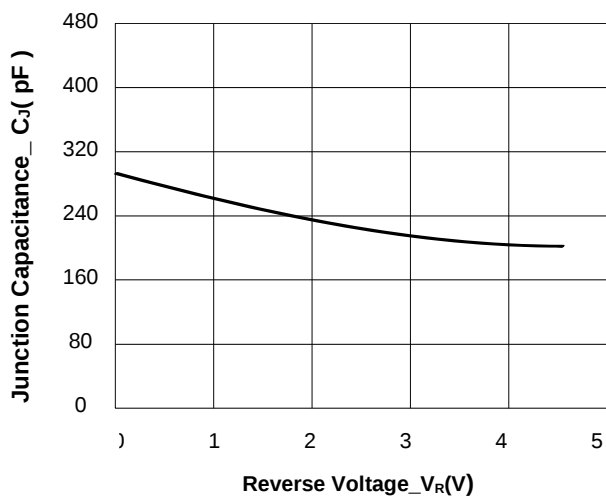
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			4.5	V	
Breakdown Voltage	V _{BR}	4.7			V	I _T = 1mA
Reverse Leakage Current	I _R			1.0	μA	V _{RWM} = 4.5V
Clamping Voltage	V _C			7.5	V	I _{PP} = 20A (8/20μs pulse)
Clamping Voltage	V _C			17	V	I _{PP} = 140A (8/20μs pulse)
Junction Capacitance	C _J		300		pF	V _R = 0V, f = 1MHz

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

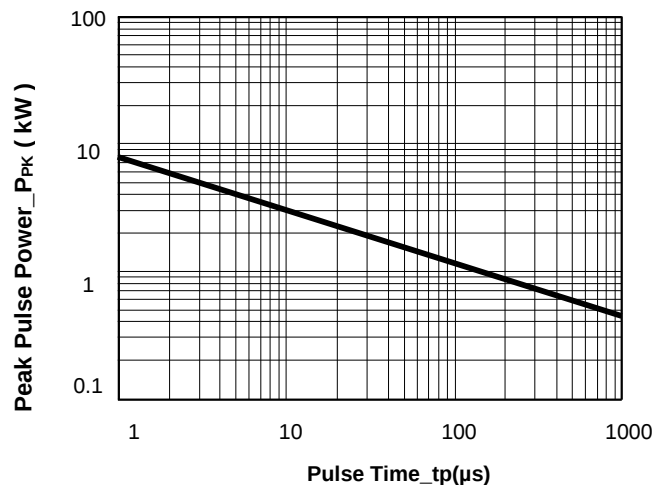


Definitions of electrical characteristics

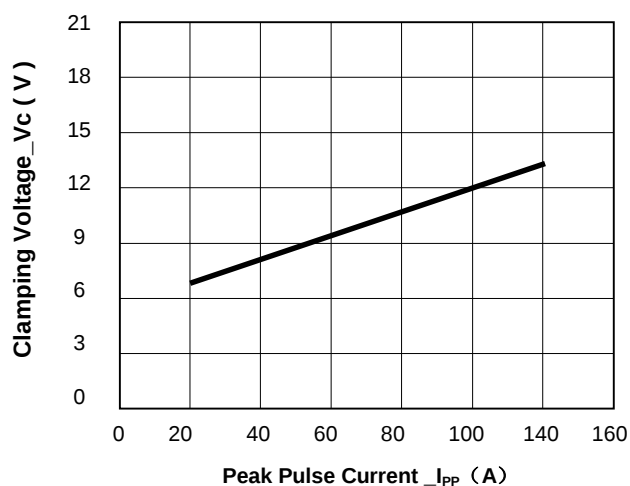
Typical Performance Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise Specified)



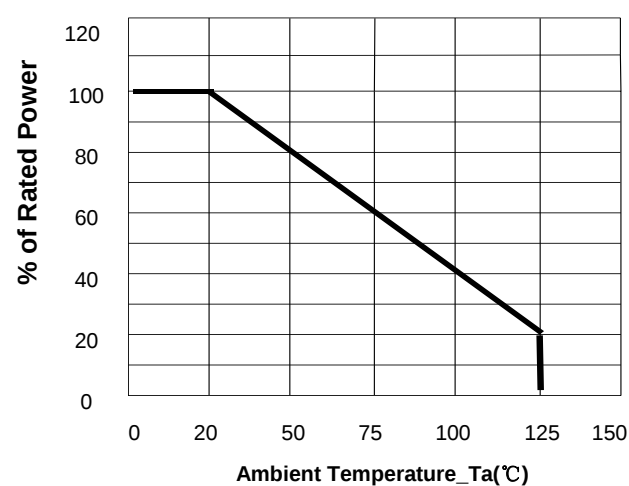
Junction Capacitance vs. Reverse Voltage



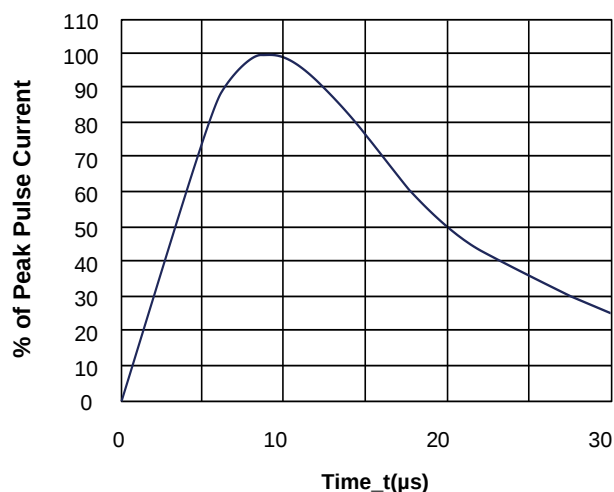
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current

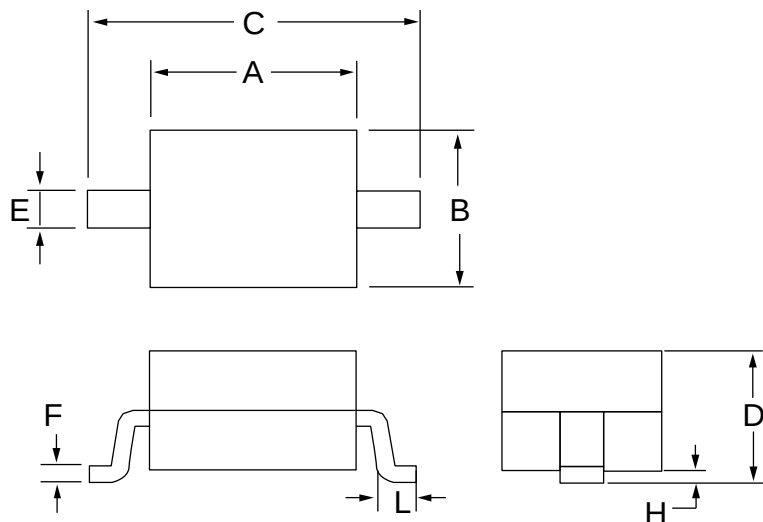


Power Derating Curve



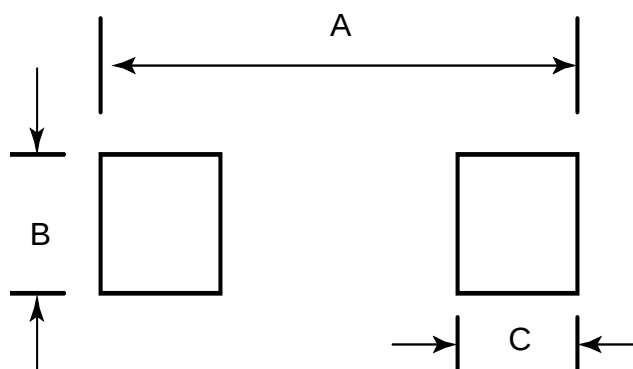
8/20 μs Pulse Waveform

SOD-323 Package Outline Drawing



SYM	DIMENSIONS				
	MILLIMETERS			INCHES	
	MIN	NOM	MAX	MIN	MAX
A	1.50	1.65	1.80	0.060	0.071
B	1.20	1.30	1.40	0.045	0.054
C	2.30	2.50	2.70	0.090	0.107
D	-		1.10	-	0.043
E	0.30		0.40	0.012	0.016
F	0.10		0.25	0.004	0.010
L	0.20		0.40	0.008	0.016
H	-		0.10	-	0.004

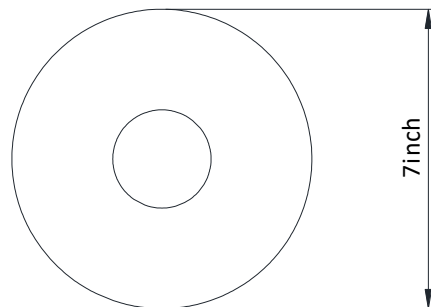
Suggested Land Pattern



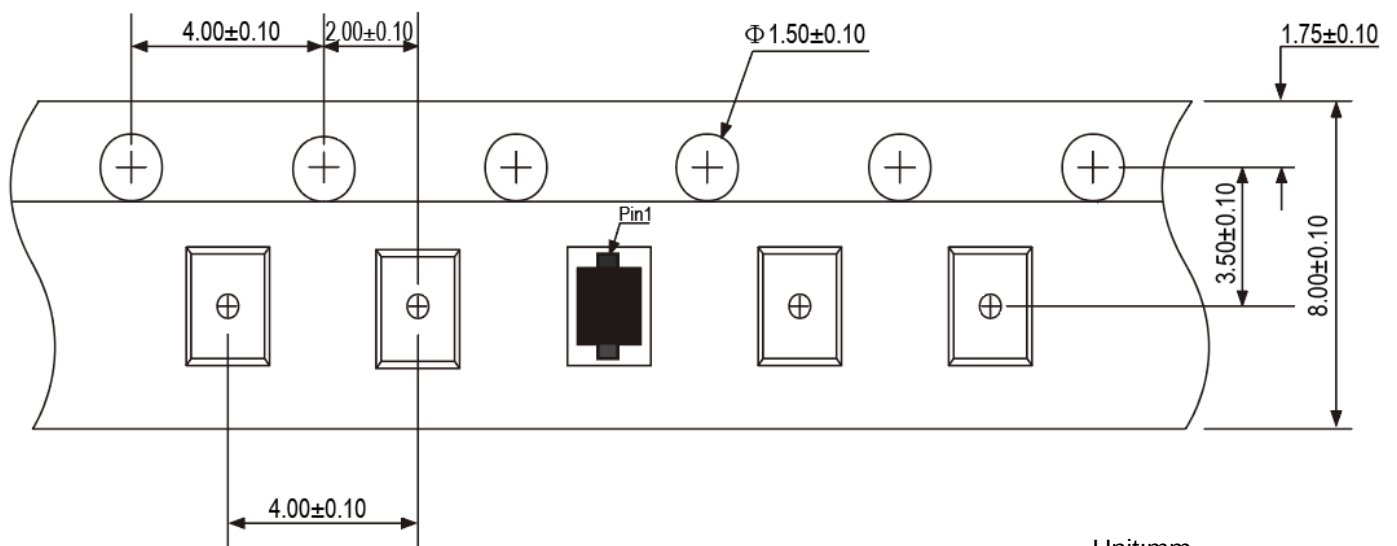
SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031

TAPE AND REEL INFORMATION

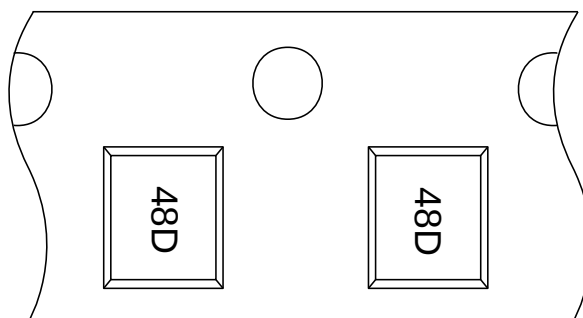
Reel Dimensions



Tape Dimensions



Unit:mm



User Direction of Feed

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